

Everything you need to know about the semiconductor memory industry, from legacy technologies to latest innovations.

Brought to you by MEMPHIS Electronic, your specialist memory distributor and DRAM module configurator. We are posting similar stories regularly on <u>LinkedIn</u>, so follow us there to stay on top of the news.

Prices Fall and Pigs Fly?

Time flies! We are in September. School has started again, and leaves are beginning to fall, but memory prices do not. At least not any longer. Just as we estimated at the beginning of the year.

Why? Because manufacturing output is still low – according to TrendForce Samsung cut back NAND production by as much as 50% in September - and this inventory clean-up is taking effect. Trendforce expects a mild price surge of 5% in NAND for Q4 2023. But looking at the demand side for 2024, Trendforce anticipates Year-over-Year bit demand growth rates for DRAM and NAND Flash of 13% and 16%, respectively.

So if you are still hoping memory prices keep falling or even stay this low for much longer, then you might wait for pigs to fly. Yes, we cautioned to be careful with this term when it comes to semiconductor innovation (if you missed it, read about it here). Who would have thought that DDR5 would come in 32Gb so soon? Or LPDDR4x would become so successful?

After all, we know memory.

But when it comes to memory market development and prices, we are quite confident we are right.

NAND Flash Prices to Stabilize & Rebound in Q4



NAND Prices to Rebound in O4

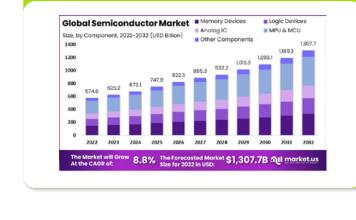
decisive step: a sweeping 50% production cut from September, with the focus mainly on processes under 128 layers. TrendForce expects other suppliers to follow suit and increase their production cutbacks in the fourth quarter to accelerate

inventory reduction. Against this background, Q4 NAND Flash

According to a recent Trendforce research, Samsung has taken a

average prices are projected to either hold firm or witness a mild surge, possibly in the ballpark of 0~5%. Aligning with TrendForce's early-year forecasts, NAND Flash prices are poised to rally ahead of DRAM. Yet, for this positive

price trajectory to sail smoothly into 2024, a sustained curtailing in production and a robust rebound in enterprise SSD purchase orders are pivotal. Read the full press release here.



Semiconductor Market Growth According to Market.us, The Global Semiconductor Market is

Memory leads Global

projected to reach a valuation of USD 1,307.7 Bn by 2032 at a CAGR of 8.8%, from USD 574.6 Bn in 2022. The growth of the market is being driven by the increasing demand for semiconductors in a variety of end-use applications. Here are some key takeaways from the semiconductor market: • The memory devices segment is expected to lead the market

- during the forecast period. The automotive segment is expected to be the fastest-growing
- market during the forecast period. • The key challenges facing the semiconductor market include
- the shortage of skilled workers, the rising cost of manufacturing, and the increasing complexity of semiconductor designs.

Find out more here.



TrendForce expects that memory suppliers will continue their strategy of scaling back production of both DRAM and NAND

the NAND Flash sector. Market demand visibility for consumer electronic is projected to remain uncertain in 1H24. Additionally, capital expenditure for general-purpose servers is expected to be weakened due to

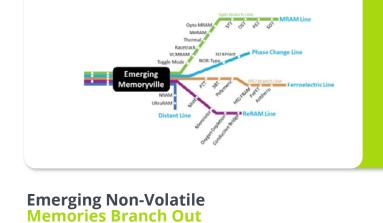
Flash in 2024, with the cutback being particularly pronounced in

competition from Al servers. Considering the low baseline set in 2023 and the current low pricing for some memory products, TrendForce anticipates for 2024 YoY bit demand growth rates for DRAM and NAND Flash to

ring supply-demand balance next year will largely hinge on suppliers' ability to exercise restraint in their production capacities. If managed effectively, this could open up an opportunity for a rebound in average memory prices. Read the full press release here.

Nonetheless, achieving effective inventory reduction and resto-

be 13% and 16%, respectively.



Magnetic RAM (MRAM) and spin transfer torque RAM (STT MRAM) are starting to replace some NOR flash and SRAM and

The rate of development and increasing product volume in STT MRAM and other MRAM technologies will gradually result in lower prices according to the 2023 report on emerging nonvolatile memory technologies from Coughlin Associates and Objective Analysis. The report projects that the total MRAM baseline annual shipping capacity will rise from an estimated 133TB in 2022 to 4.56EB in 2033. Total MRAM revenues are expected to increase

could possibly displace some DRAM within the next few years.

Much of this revenue gain will be at the expense of SRAM, NOR flash and some DRAM, although STT-RAM is developing its own special place in the pantheon of shipping memory technologies.

from \$118M in 2022 to about \$98.3B by 2033 compared to

projected revenues for DRAM and NAND.

Read more here.



As vital as DRAMs are for virtually all designs, they are not immune to errors and some of those only occur after hours of use once a product is widely shipped and deployed. Find out how to avoid

importantly, what was the impact?

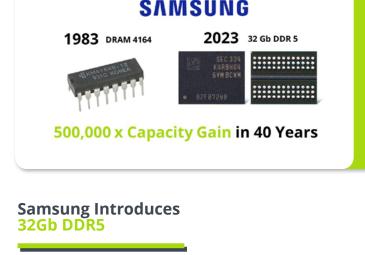
All About Circuits. On October 5 at 10 am ET / 4pm CET the long-term expert in the

costly recalls and join Peter Pöchmüller, CEO of MEMPHIS and

Neumonda, for his session during the Industry Tech Days held by

DRAM industry introduces a revolutionary new approach to application-specific DRAM testing and its impact on the industry. Read more and register here.

More Choice of LPDDR4x



of its 12nm-class 16Gb DDR5 DRAM. Having developed its first 64-kilobit (Kb) DRAM in 1983, Samsung has now succeeded in enhancing its DRAM capacity by a

factor of 500,000 over the last 40 years.

to 128GB modules with 16Gb DRAM.

Previously, DDR5 128GB DRAM modules manufactured using 16Gb DRAM required the Through Silicon Via (TSV) process. However, by using Samsung's 32Gb DRAM, the 128GB module can now be produced without using the TSV process, while

reducing power consumption by approximately 10% compared

Samsung has developed the industry's first and highest-ca-

pacity 32-gigabit (Gb) DDR5 DRAM using 12 nm-class process

technology only a few months after taking up mass production

Read the full press release <u>here</u>.

SAMSUNG

Meet MEMPHIS at EDS 2023



The LPDDR4x components are also offered with industrial tem-

perature grades which range from -40C to +95C. They feature a maximum data rate performance of up to 4266 Mbps and an operating I/O (VDDQ) voltage as low as 0.6V. These savings turned out to be compelling for applications even when considering the added cost to cater for a new voltage I/O

power supply in the system. Read the full press release here.

UK, on October 11 and 12? Then make sure you swing by our booth K53. You won't find a memory portfolio that is as comprehensive as

ours and we will provide insights into the highly volatile memory market. And if you can't find just the right DRAM Module, we will configure it for you. Plus, we will provide insights into the highly volatile memory

Are you going to Engineering Design Show 2023 in Coventry,

Learn more <u>here</u>.

market. Based on our over 30 years of experience in the global

pricing and delivery trends regarding DRAM and Flash compo-

distribution of memory products, we can advise on current

nents as well as modules.

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